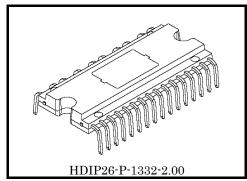
TOSHIBA Intelligent Power Device

High Voltage Monolithic Silicon Power IC

TPD4135AK

The TPD4135AK is a DC brush less motor driver using high voltage PWM control. It is fabricated by high voltage SOI process. It is three-shunt resistor circuit for current sensing. It contains level shift high-side driver, low-side driver, IGBT outputs, FRDs and protective functions for under voltage protection circuits and thermal shutdown circuit. It is easy to control a DC brush less motor by just putting logic inputs from a MPU or motor controller to the TPD4135AK.



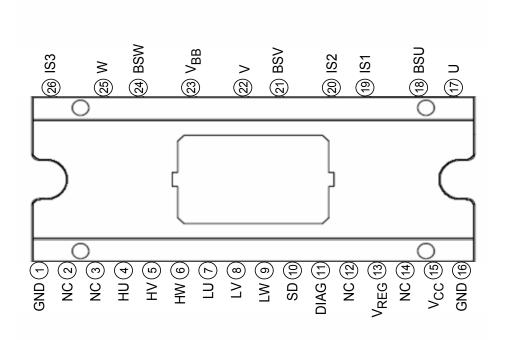
Weight: 3.8 g (typ.)

Features

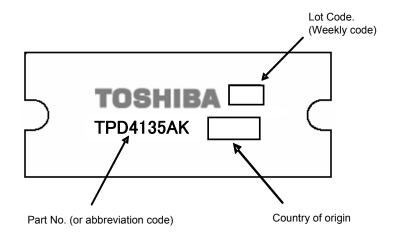
- High voltage power side and low voltage signal side terminal are separated.
- It is the best for current sensing in three shunt resistance.
- · Bootstrap circuit gives simple high-side supply.
- Bootstrap diodes are built in.
- A dead time can be set as a minimum of $1.4~\mu s$, and it is the best for a Sine-wave from drive.
- 3-phase bridge output using IGBTs.
- FRDs are built in.
- Included under voltage protection and thermal shutdown.
- The regulator of 7 V (typ.) is built in.
- Package: 26-pin DIP.

This product has a MOS structure and is sensitive to electrostatic discharge. When handling this product, ensure that the environment is protected against electrostatic discharge.

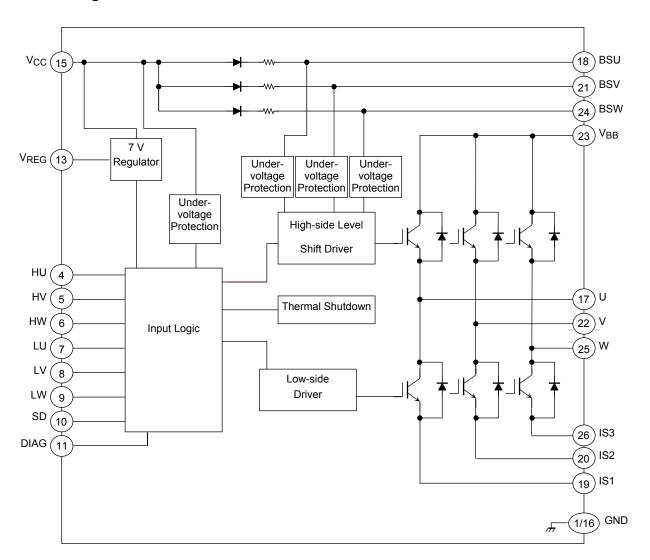
Pin Assignment



Marking



Block Diagram

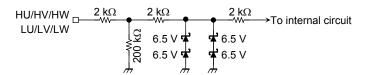


Pin Description

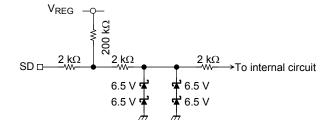
| Pin No. | Symbol | Pin Description |
|---------|------------------|--|
| 1 | GND | Ground pin. |
| 2 | NC | Unused pin, which is not connected to the chip internally. |
| 3 | NC | Unused pin, which is not connected to the chip internally. |
| 4 | HU | The control terminal of IGBT by the high side of U. It turns off less than 1.5V. It turns on more than 2.5V. |
| 5 | HV | The control terminal of IGBT by the high side of V. It turns off less than 1.5V. It turns on more than 2.5V. |
| 6 | HW | The control terminal of IGBT by the high side of W. It turns off less than 1.5V. It turns on more than 2.5V. |
| 7 | LU | The control terminal of IGBT by the low side of U. It turns off less than 1.5V. It turns on more than 2.5V. |
| 8 | LV | The control terminal of IGBT by the low side of V. It turns off less than 1.5V. It turns on more than 2.5V. |
| 9 | LW | The control terminal of IGBT by the low side of W. It turns off less than 1.5V. It turns on more than 2.5V. |
| 10 | SD | Input pin of external protection. ("L" active, It doesn't have hysteresis) |
| 11 | DIAG | With the diagnostic output terminal of open drain, a pull-up is carried out by resistance. It turns on at the time of unusual. |
| 12 | NC | Unused pin, which is not connected to the chip internally. |
| 13 | V _{REG} | 7V regulator output pin. |
| 14 | NC | Unused pin, which is not connected to the chip internally. |
| 15 | V _{CC} | Control power supply pin. (15V typ.) |
| 16 | GND | Ground pin. |
| 17 | U | U-phase output pin. |
| 18 | BSU | U-phase bootstrap capacitor connecting pin. |
| 19 | IS1 | U-phase IGBT emitter and FRD anode pin. |
| 20 | IS2 | V-phase IGBT emitter and FRD anode pin. |
| 21 | BSV | V-phase bootstrap capacitor connecting pin. |
| 22 | V | V-phase output pin. |
| 23 | V _{BB} | High-voltage power supply input pin. |
| 24 | BSW | W-phase bootstrap capacitor connecting pin. |
| 25 | W | W-phase output pin. |
| 26 | IS3 | W-phase IGBT emitter and FRD anode pin. |

Equivalent Circuit of Input Pins

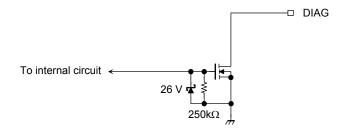
Internal circuit diagram of HU, HV, HW, LU, LV, LW input pins



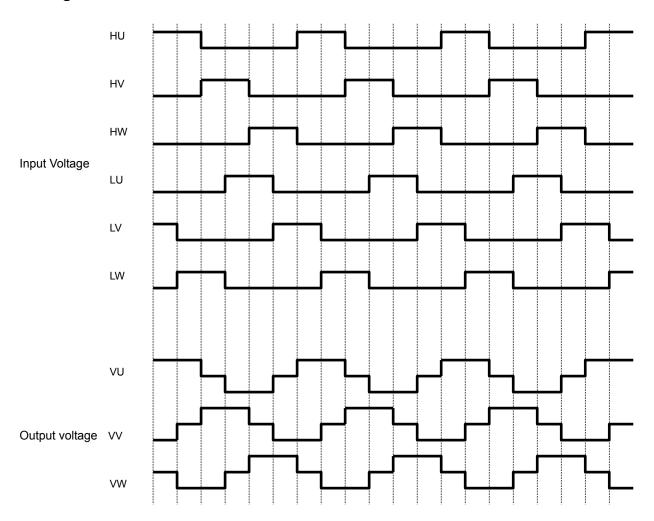
Internal circuit diagram of SD pin



Internal circuit diagram of DIAG pin



Timing Chart



6

Truth Table

| | Input | | | High side | | | Low side | | | DIAG | | | | |
|-------------------------------|-------|----|----|-----------|----|----|----------|---------|---------|---------|---------|---------|---------|------|
| Mode | HU | HV | HW | LU | LV | LW | SD | U phase | V phase | W phase | U phase | V phase | W phase | DIAG |
| Normal | Н | L | L | L | Н | L | Н | ON | OFF | OFF | OFF | ON | OFF | OFF |
| | Η | Ш | L | Ш | L | Н | Η | ON | OFF | OFF | OFF | OFF | ON | OFF |
| | L | Η | L | L | L | Н | Η | OFF | ON | OFF | OFF | OFF | ON | OFF |
| | L | Н | L | Н | L | L | Н | OFF | ON | OFF | ON | OFF | OFF | OFF |
| | L | L | Н | Н | L | L | Н | OFF | OFF | ON | ON | OFF | OFF | OFF |
| | L | L | Н | L | Н | L | Н | OFF | OFF | ON | OFF | ON | OFF | OFF |
| Thermal shutdown | Н | L | L | L | Н | L | Н | OFF | OFF | OFF | OFF | OFF | OFF | ON |
| | Н | L | L | L | L | Н | Н | OFF | OFF | OFF | OFF | OFF | OFF | ON |
| | L | Н | L | L | L | Н | Н | OFF | OFF | OFF | OFF | OFF | OFF | ON |
| | L | Н | L | Н | L | L | Н | OFF | OFF | OFF | OFF | OFF | OFF | ON |
| | L | L | Н | Н | L | L | Н | OFF | OFF | OFF | OFF | OFF | OFF | ON |
| | L | L | Н | L | Н | L | Н | OFF | OFF | OFF | OFF | OFF | OFF | ON |
| V _{CC} Under-voltage | Н | L | L | L | Н | L | Н | OFF | OFF | OFF | OFF | OFF | OFF | ON |
| | Н | L | L | L | L | Н | Н | OFF | OFF | OFF | OFF | OFF | OFF | ON |
| | L | Н | L | L | L | Н | Н | OFF | OFF | OFF | OFF | OFF | OFF | ON |
| | L | Н | L | Н | L | L | Н | OFF | OFF | OFF | OFF | OFF | OFF | ON |
| | L | L | Н | Н | L | L | Н | OFF | OFF | OFF | OFF | OFF | OFF | ON |
| | L | L | Н | L | Н | L | Н | OFF | OFF | OFF | OFF | OFF | OFF | ON |
| V _{BS} Under-voltage | Н | L | L | L | Н | L | Н | OFF | OFF | OFF | OFF | ON | OFF | OFF |
| | Н | L | L | L | L | Н | Н | OFF | OFF | OFF | OFF | OFF | ON | OFF |
| | L | Н | L | L | L | Н | Н | OFF | OFF | OFF | OFF | OFF | ON | OFF |
| | L | Н | L | Н | L | L | Н | OFF | OFF | OFF | ON | OFF | OFF | OFF |
| | L | L | Н | Н | L | L | Н | OFF | OFF | OFF | ON | OFF | OFF | OFF |
| | L | L | Н | L | Н | L | Н | OFF | OFF | OFF | OFF | ON | OFF | OFF |
| SD | * | * | * | * | * | * | L | OFF | OFF | OFF | OFF | OFF | OFF | ON |

2010-09-27

Absolute Maximum Ratings (Ta = 25°C)

| Characteristics | Symbol | Rating | Unit | |
|--------------------------------|----------------------|--------------------|------|--|
| Power supply voltage | V_{BB} | 500 | V | |
| Power supply voltage | V _{CC} | 18 | V | |
| Output current (DC) | l _{out} | 3 | Α | |
| Output current (pulse 1ms) | l _{outp} | 6 | Α | |
| Input voltage | V _{IN} | -0.5 to 7 | ٧ | |
| V _{REG} current | I _{REG} | 50 | mA | |
| DIAG voltage | V_{DIAG} | 20 | V | |
| DIAG current | I _{DIAG} | 20 | mA | |
| Power dissipation | Powert) | 40 | W | |
| (IGBT 1 phase (Tc = 25°C)) | P _{C(IGBT)} | 40 | | |
| Power dissipation | Po(EDD) | 26 | W | |
| (FRD1 phase (Tc = 25°C)) | P _{C(FRD)} | 20 | | |
| Operating junction temperature | T _{jopr} | -40 to 135 | ů | |
| Junction temperature | Tj | T _j 150 | | |
| Storage temperature | T _{stg} | -55 to 150 | °C | |

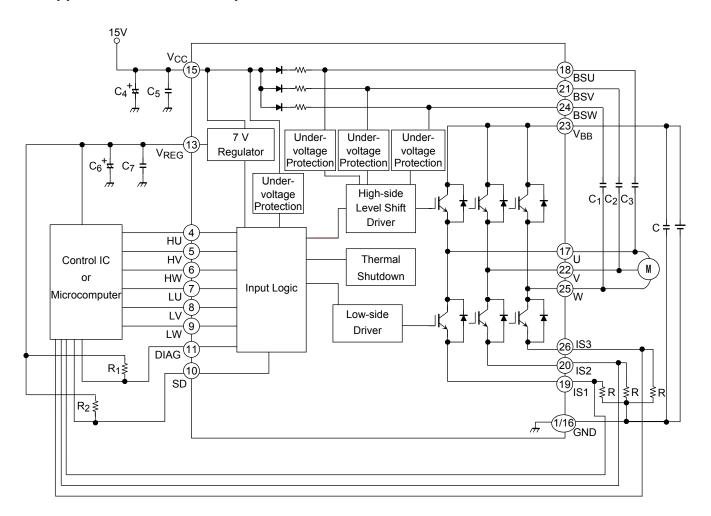
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Electrical Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit | | | |
|---|-----------------------|---|------|------|------|------|--|--|--|
| On another management and the man | V _{BB} | _ | 50 | 280 | 450 | | | | |
| Operating power supply voltage | V _{CC} | _ | 13.5 | 15 | 16.5 | V | | | |
| Comment discipation | I _{BB} | V _{BB} = 450 V | _ | _ | 0.5 | A | | | |
| Current dissipation | Icc | V _{CC} = 15 V | _ | 0.8 | 5 | mA | | | |
| Pastatran Current dissination | I _{BS} (ON) | V _{BS} = 15 V, high side ON — | | 200 | 410 | Δ | | | |
| Bootstrap Current dissipation | I _{BS (OFF)} | V _{BS} = 15 V, high side OFF | _ | 170 | 370 | μΑ | | | |
| Input voltage | V _{IH} | V _{IN} = "H", V _{CC} = 15 V | 2.5 | _ | _ | V | | | |
| Input voltage | V _{IL} | V _{IN} = "L" , V _{CC} = 15 V | _ | _ | 1.5 | | | | |
| SD input voltage | V _{SD} | V _{CC} = 15 V | _ | 2.5 | _ | V | | | |
| Input current | liH | V _{IN} = 5 V | _ | _ | 150 | | | | |
| Input current | Ι _{ΙL} | V _{IN} = 0 V | _ | _ | 100 | μΑ | | | |
| CD largest comment | I _{SDH} | V _{IN} = 5 V | _ | _ | 100 | μА | | | |
| SD Input current | I _{SDL} | V _{IN} = 0 V | _ | _ | 150 | | | | |
| Outrot ask mation with an | V _{CEsat} H | $V_{CC} = 15 \text{ V}, I_C = 1.5 \text{ A}, \text{ high side}$ | _ | 2.1 | 2.8 | \/ | | | |
| Output saturation voltage | V _{CEsat} L | $V_{CC} = 15 \text{ V}, I_C = 1.5 \text{ A}, \text{ low side}$ | _ | 2.1 | 2.8 | V | | | |
| EDD forward walks as | V _F H | I _F = 1.5 A, high side | _ | 1.9 | 2.8 | V | | | |
| FRD forward voltage | V _F L | I _F = 1.5 A, low side | _ | 1.9 | 2.8 | | | | |
| BSD forward voltage | V _{F (BSD)} | I _F = 500 μA | _ | 0.8 | 1.2 | V | | | |
| Regulator voltage | V _{REG} | V _{CC} = 15 V, I _{REG} = 30 mA | 6.5 | 7 | 7.5 | V | | | |
| Thermal shutdown temperature | TSD | V _{CC} = 15 V | 135 | _ | 185 | °C | | | |
| Thermal shutdown hysteresis | ΔTSD | V _{CC} = 15 V | _ | 50 | _ | °C | | | |
| V _{CC} under voltage protection | V _{CC} UVD | _ | 10 | 11 | 12 | V | | | |
| V _{CC} under voltage protection recovery | V _{CC} UVR | _ | 10.5 | 11.5 | 12.5 | V | | | |
| V _{BS} under voltage protection | V _{BS} UVD | _ | 8 | 9 | 9.5 | V | | | |
| V _{BS} under voltage protection recovery | V _{BS} UVR | _ | 8.5 | 9.5 | 10.5 | V | | | |
| DIAG saturation voltage | V _{DIAGsat} | I _{DIAG} = 5 mA | _ | _ | 0.5 | V | | | |
| Output on delay time | t _{on} | V _{BB} = 280 V, V _{CC} = 15 V, I _C = 1.5 A | _ | 1.8 | 3 | μS | | | |
| Output off delay time | t _{off} | V _{BB} = 280 V, V _{CC} = 15 V, I _C = 1.5 A | _ | 1.3 | 3 | μS | | | |
| Dead time | t _{dead} | V _{BB} = 280 V, V _{CC} = 15 V, I _C = 1.5 A | 1.4 | _ | _ | μS | | | |
| FRD reverse recovery time | t _{rr} | V _{BB} = 280 V, V _{CC} = 15 V, I _C = 1.5 A | _ | 200 | _ | ns | | | |

Application Circuit Example



External Parts

Typical external parts are shown in the following table.

| Part | Typical | Purpose | Remarks | |
|--|--------------|---|----------|--|
| C ₁ , C ₂ , C ₃ | 25 V/2.2 μF | Bootstrap capacitor | (Note 1) | |
| C ₄ | 25 V/10 μF | V _{CC} power supply stability | (Note 2) | |
| C ₅ | 25 V/0.1 μF | V _{CC} for surge absorber | (Note 2) | |
| C ₆ | 25 V/1 μF | V _{REG} power supply stability | (Note 2) | |
| C ₇ | 25 V/1000 pF | V _{REG} for surge absorber | (Note 2) | |
| R ₁ | 5.1 kΩ | DIAG pin pull-up resistor | (Note 3) | |
| R ₂ | 10 kΩ | SD pin pull-up resistor | - | |

- Note 1: The required bootstrap capacitance value varies according to the motor drive conditions. The capacitor is biased by V_{CC} and must be sufficiently derated for it.
- Note 2: When using this product, adjustment is required in accordance with the use environment. When mounting, place as close to the base of this product leads as possible to improve the ripple and noise elimination.
- Note 3: The DIAG pin is open drain. If not using the DIAG pin, connect to the GND.

Handling precautions

- (1) Please control the input signal in the state to which the V_{CC} voltage is steady. Both of the order of the V_{BB} power supply and the V_{CC} power supply are not cared about either. Note that if the power supply is switched off as described above, this product may be destroyed if the current regeneration route to the V_{BB} power supply is blocked when the V_{BB} line is disconnected by a relay or similar while the motor is still running.
- (2) The excess voltage such as the voltage surge which exceed the maximum rating is added, for example, may destroy the circuit. Accordingly, be careful of handling this product or of surge voltage in its application environment.

Description of Protection Function

(1) Under voltage protection

This product incorporates under voltage protection circuits to prevent the IGBT from operating in unsaturated mode when the $V_{\rm CC}$ voltage or the $V_{\rm BS}$ voltage drops. When the $V_{\rm CC}$ power supply falls to this product internal setting $V_{\rm CC}UVD$ (=11 V typ.), all IGBT outputs shut down regardless of the input. This protection function has hysteresis. When the $V_{\rm CC}$ power supply reaches 0.5 V higher than the shutdown voltage ($V_{\rm CC}UVR$ (=11.5 V typ.)), this product is automatically restored and the IGBT is turned on again by the input. DIAG output is reversed at the time of $V_{\rm CC}$ under-voltage protection. When the $V_{\rm CC}$ power supply is less than 7 V, DIAG output isn't sometimes reversed. When the $V_{\rm BS}$ supply voltage drops $V_{\rm BS}UVD$ (=9 V typ.), the high-side IGBT output shuts down.

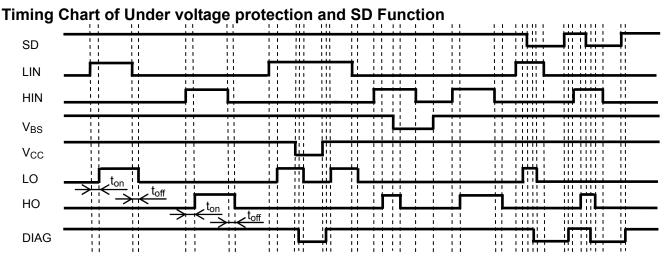
When the VBS supply voltage reaches 0.5 V higher than the shutdown voltage (VBSUVR (=9.5 V typ.)), the IGBT is turned on again by the input signal.

(2) Thermal shutdown

This product incorporates a thermal shutdown circuit to protect itself against the abnormal state when its temperature rises excessively. When the temperature of this chip rises to the internal setting TSD due to external causes or internal heat generation, all IGBT outputs shut down regardless of the input. This protection function has hysteresis ΔTSD (=50°C typ.). When the chip temperature falls to TSD – ΔTSD , the chip is automatically restored and the IGBT is turned on again by the input. Because the chip contains just one temperature detection location, when the chip heats up due to the IGBT, for example, the differences in distance from the detection location in the IGBT (the source of the heat) cause differences in the time taken for shutdown to occur. Therefore, the temperature of the chip may rise higher than the thermal shutdown temperature when the circuit started to operate.

(3) SD pin

SD pin is the input signal pin to shut down the internal output IGBT. Output of all IGBT is shut down after delay times (2 μ s typ.) when "L" signal is input to the SD pin from external circuit (MCU etc.). It is possible to shut down IC when overcurrent and others is detected by external circuit. Shut down state is released by all of IC input signal "L". At open state of SD pin, shut down function can not operate.



Note: The above timing chart is considering the delay time.

Safe Operating Area

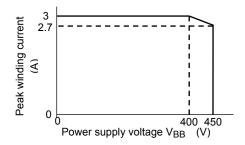
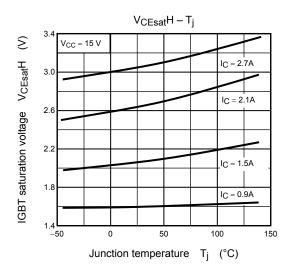
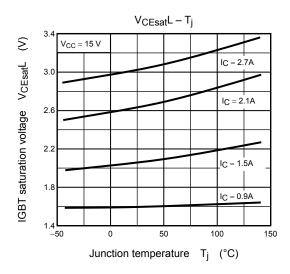


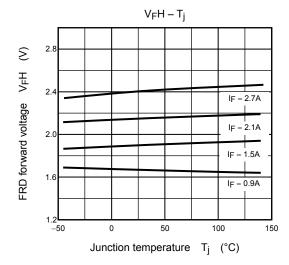
Figure 1 SOA at Tj = 135 °C

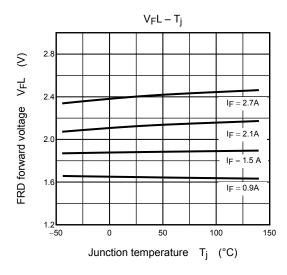
Note 1: The above safe operating areas are Tj = 135 °C (Figure 1).

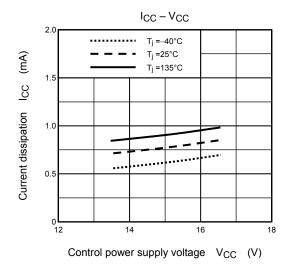
12 2010-09-27

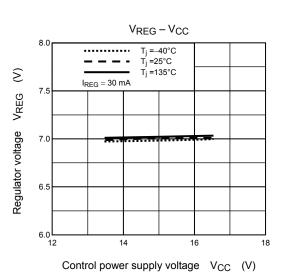




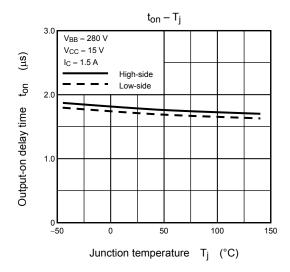


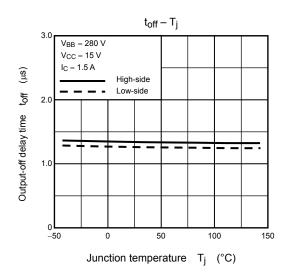


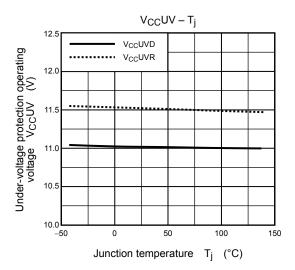


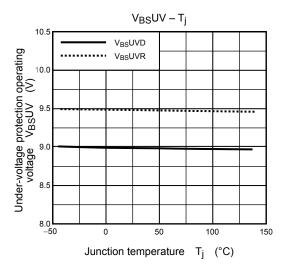


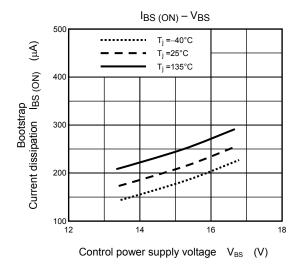
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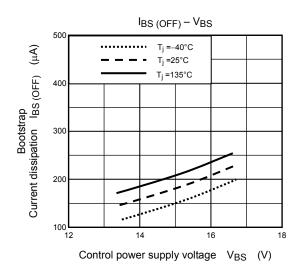


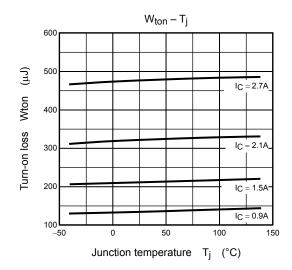


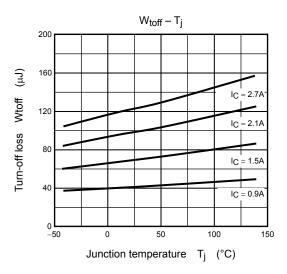






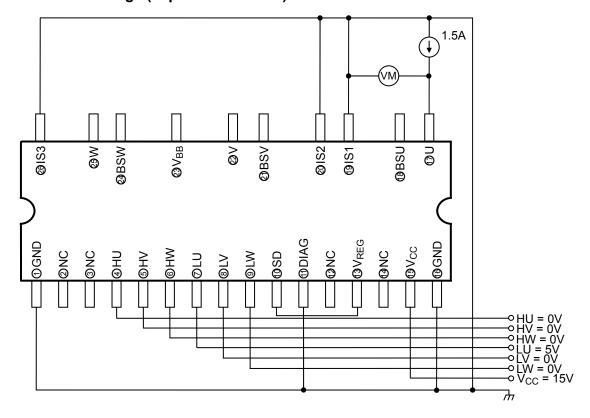




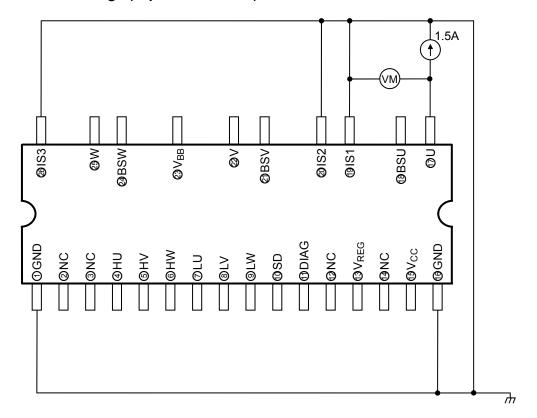


Test Circuits

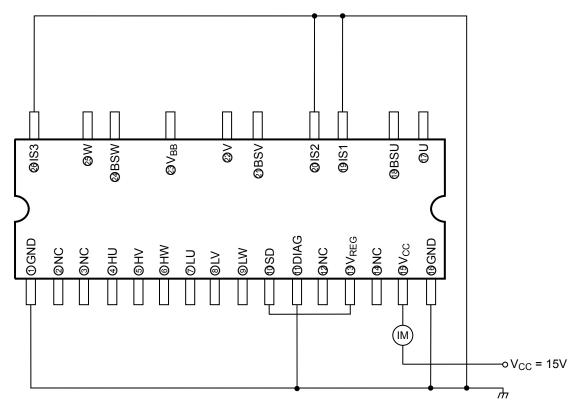
IGBT Saturation Voltage (U-phase low side)



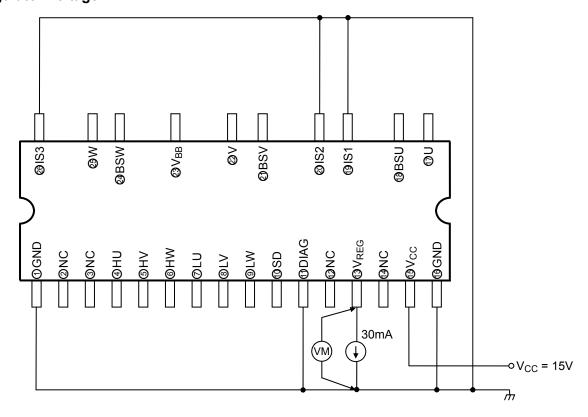
FRD Forward Voltage (U-phase low side)



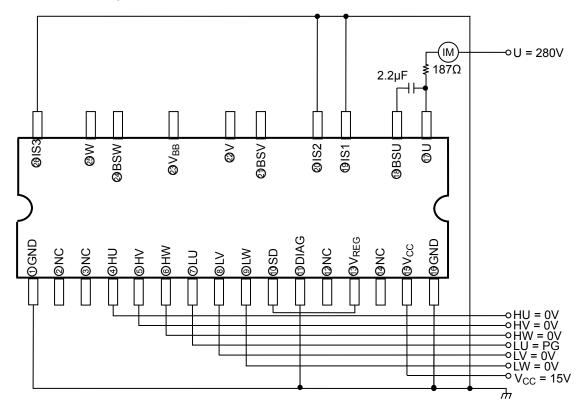
V_{CC} Current Dissipation

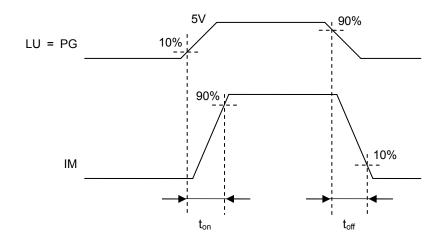


Regulator Voltage

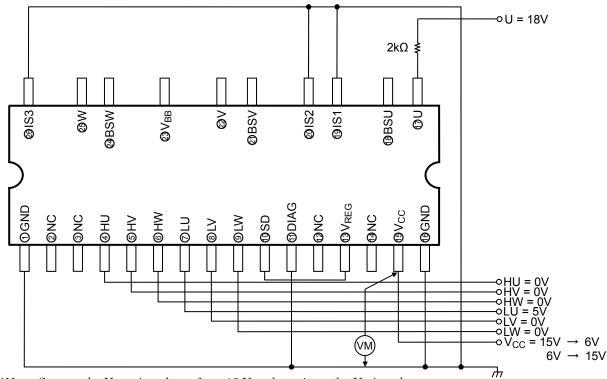


Output ON/OFF Delay Time (U-phase low side)





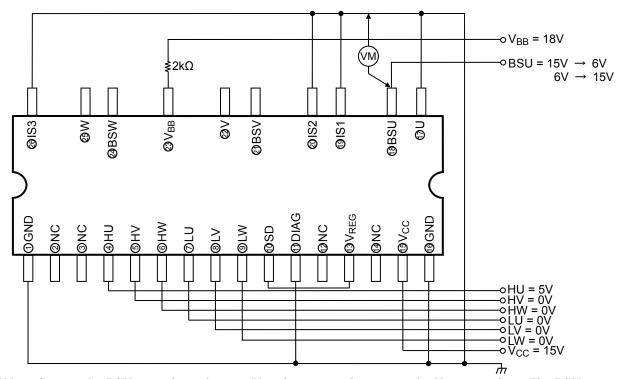
V_{CC} Under-voltage Protection Operating/Recovery Voltage (U-phase low side)



^{*}Note: Sweeps the VCC pin voltage from 15 V and monitors the U pin voltage.

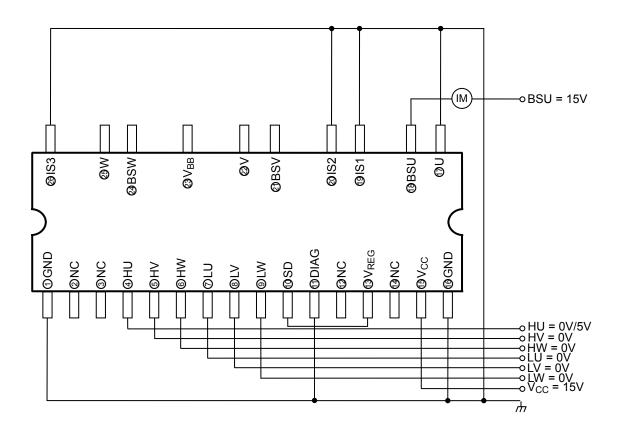
The V_{CC} pin voltage when output is off defines the under voltage protection operating voltage. Also sweeps from 6 V to increase. The V_{CC} pin voltage when output is on defines the under voltage protection recovery voltage.

V_{BS} Under voltage Protection Operating/Recovery Voltage (U-phase high side)

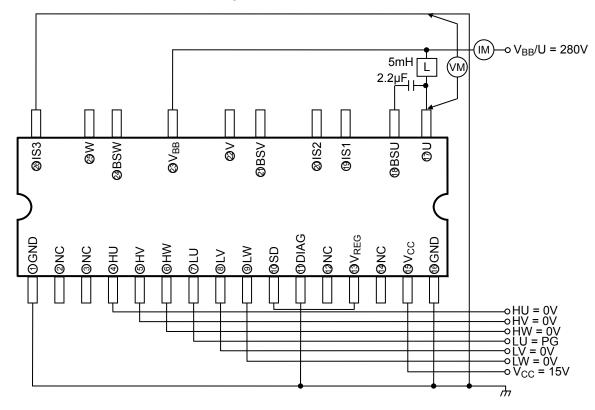


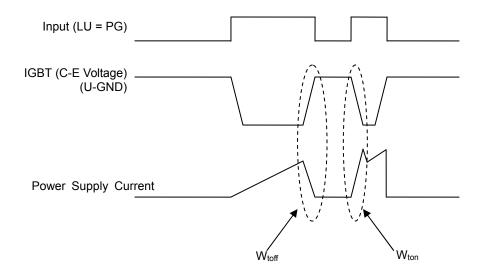
*Note: Sweeps the BSU pin voltage from 15 V to decrease and monitors the V_{BB} pin voltage. The BSU pin voltage when output is off defines the under voltage protection operating voltage. Also sweeps the BSU pin voltage from 6 V to increase and change the HU pin voltage at 5 V \rightarrow 0 V \rightarrow 5 V each time. It repeats similarly output is on. When the BSU pin voltage when output is on defines the under voltage protection recovery voltage.

Bootstrap Current Dissipation (U-phase high side)



Turn-On/Off Loss (low side IGBT + high side FRD)

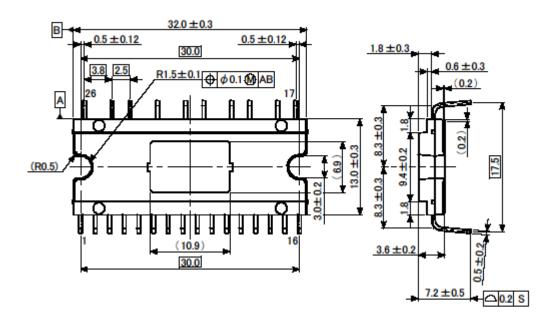


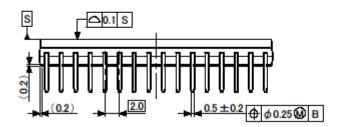


Package Dimensions

HDIP26-P-1332-2.00

Unit: mm





Weight: 3.8 g (typ.)

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